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PS22053

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INTEGRATED POWER FUNCTIONS

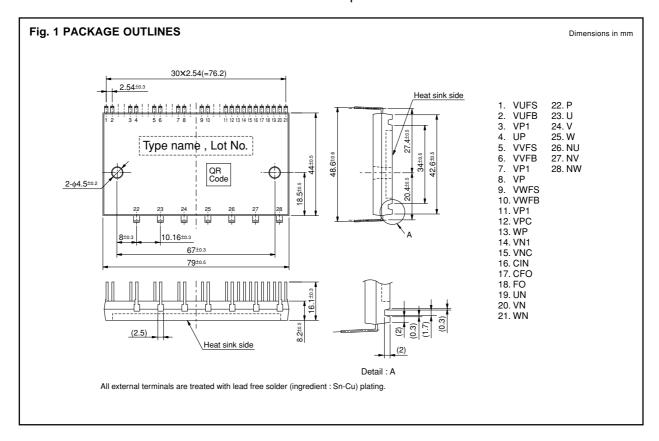
1200V/10A low-loss 4^{th} generation IGBT inverter bridge for 3 phase DC-to-AC power conversion

INTEGRATED DRIVE, PROTECTION AND SYSTEM CONTROL FUNCTIONS

- For upper-leg IGBTs :Drive circuit, High voltage high-speed level shifting, Control supply under-voltage (UV) protection.
- For lower-leg IGBTs: Drive circuit, Control supply under-voltage protection (UV), Short circuit protection (SC).
- Fault signaling: Corresponding to an SC fault (Lower-side IGBT) or a UV fault (Lower-side supply).
- Input interface: 5V line CMOS/TTL compatible (High active logic).

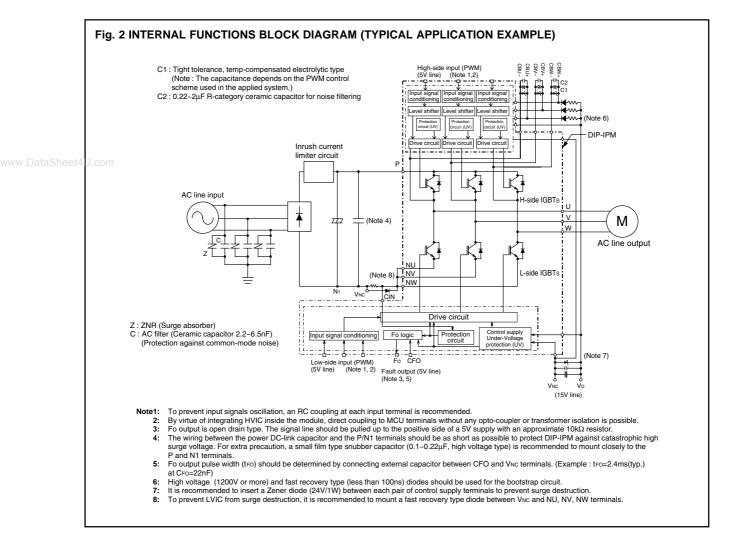
APPLICATION

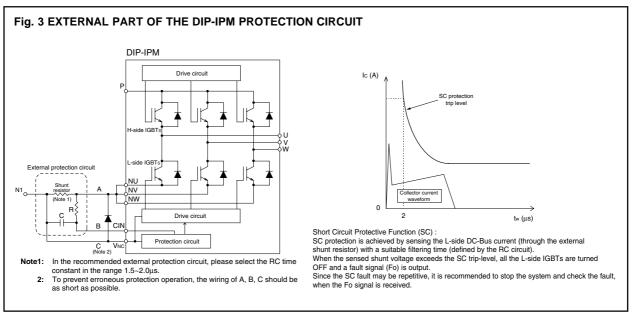
AC400V 0.2kW~0.75kW inverter drive for small power motor control.





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$\textbf{MAXIMUM RATINGS} \ (T_j = 25^{\circ}C, \ unless \ otherwise \ noted)$

INVERTER PART

| Symbol | Parameter | Condition | Ratings | Unit |
|------------|------------------------------------|------------------------------|------------------|------|
| Vcc | Supply voltage | Applied between P-NU, NV, NW | 900 | V |
| VCC(surge) | Supply voltage (surge) | Applied between P-NU, NV, NW | 1000 | V |
| VCES | Collector-emitter voltage | | 1200 | V |
| ±lc | Each IGBT collector current | Tc = 25°C | 10 | Α |
| ±ICP | Each IGBT collector current (peak) | Tc = 25°C, less than 1ms | 20 | Α |
| Pc | Collector dissipation | Tc = 25°C, per 1 chip | 50.0 | W |
| Лфот | Junction temperature | (Note 1) | −20 ~+125 | °C |

Note 1 : The maximum junction temperature rating of the power chips integrated within the DIP-IPM is 150° C (@ Tc $\leq 100^{\circ}$ C) however, to ensure safe operation of the DIP-IPM, the average junction temperature should be limited to Tj(ave) $\leq 125^{\circ}$ C (@ Tc $\leq 100^{\circ}$ C).

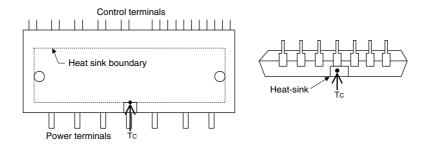
CONTROL (PROTECTION) PART

| Symbol | Parameter | Condition | Ratings | Unit |
|--------|-------------------------------|---|-------------|------|
| VD | Control supply voltage | Applied between VP1-VPC, VN1-VNC | 20 | V |
| VDB | Control supply voltage | Applied between Vufb-Vufs, Vvfb-Vvfs, Vwfb-Vwfs | 20 | V |
| Vin | Input voltage | Applied between UP, VP, WP-VPC, UN, VN, WN-VNC | -0.5~VD+0.5 | ٧ |
| VFO | Fault output supply voltage | Applied between Fo-VNC | -0.5~VD+0.5 | V |
| IFO | Fault output current | Sink current at Fo terminal | 1 | mA |
| Vsc | Current sensing input voltage | Applied between CIN-VNC | -0.5~VD+0.5 | V |

TOTAL SYSTEM

| Symbol | Parameter | Condition | Ratings | Unit |
|-----------|--|--|------------------|------|
| VCC(PROT) | Self protection supply voltage limit (short circuit protection capability) | $VD = 13.5 \sim 16.5 V$, Inverter part $T_j = 125 ° C$, non-repetitive, less than 2 μs | 800 | ٧ |
| Tc | Module case operation temperature | (Note 2) | − 20~+100 | °C |
| Tstg | Storage temperature | | − 40~+125 | °C |
| Viso | Isolation voltage | 60Hz, Sinusoidal, AC 1 minute, connection pins to heat-sink plate | 2500 | Vrms |

Note 2: TC MEASUREMENT POINT





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THERMAL RESISTANCE

| Symbol Parameter | Davamatav | Condition | Limits | | | Limit |
|------------------|--|--|--------|------|-------|-------|
| | Condition | | Тур. | Max. | Unit | |
| Rth(j-c)Q | Junction to case thermal Inverter IGBT part (per 1/6 module) | | _ | _ | 2.00 | °C/W |
| Rth(j-c)F | resistance | Inverter FWDi part (per 1/6 module) | | _ | 2.67 | °C/W |
| Rth(c-f) | Contact thermal resistance (Note 3) | Case to fin, (per 1 module) thermal grease applied | _ | _ | 0.047 | °C/W |

Note 3: Grease with good thermal conductivity and long-term endurance should be applied evenly with about +100μm~+200μm on the contacting surface of DIP-IPM and heat-sink.

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ELECTRICAL CHARACTERISTICS ($T_j = 25^{\circ}C$, unless otherwise noted)

INVERTER PART

| Cumple of | Davamatar | Condition | | Limits | | | Limit | |
|------------------|------------------------------|----------------------------|--|--------|------|------|-------|--|
| Symbol | Parameter | | Condition | | Тур. | Max. | Unit | |
| VCE(cot) | Collector-emitter saturation | VD = VDB = 15V | Tj = 25°C | _ | 2.7 | 3.4 | | |
| VCE(sat) voltage | VIN = 5V, IC = 10A | Tj = 125°C | _ | 2.5 | 3.2 | V | | |
| VEC | FWDi forward voltage | -IC = 10A, VIN = 0V | | _ | 2.5 | 3.0 | V | |
| ton | | Vcc = 600V, VD = VDB = 15V | | 0.8 | 1.5 | 2.2 | μs | |
| trr | | | | _ | 0.2 | _ | μs | |
| tc(on) | Switching times | IC = 10A, Tj = 125°C, VII | Ic = 10A, Tj = 125°C, VIN = $0 \leftrightarrow 5V$ | | 0.4 | 0.7 | μs | |
| toff | | Inductive load (upper-lo | wer arm) | _ | 2.8 | 3.8 | μs | |
| tc(off) | | | | _ | 0.4 | 0.7 | μs | |
| ICES | Collector-emitter cut-off | VCE = VCES | Tj = 25°C | _ | | 1 | mA | |
| 1020 | current | VCE = VCES | Tj = 125°C | _ | _ | 10 | 1117 | |

CONTROL (PROTECTION) PART

| Symbol | Parameter | Condition | | | Limits | | | Unit |
|----------|------------------------------|---|---|----------------------------|--------|------|-------|------|
| Syllibol | Farameter | Condition | | Min. | Тур. | Max. | Offic | |
| | | VD = VDB = 15V | Total o | of VP1-VPC, VN1-VNC | _ | _ | 3.70 | mA |
| ID | Circuit current | VIN = 5V | VUFB-\ | VUFS, VVFB-VVFS, VWFB-VWFS | _ | _ | 1.30 | mA |
| טו | Circuit current | VD = VDB = 15V | Total o | f VP1-VPC, VN1-VNC | _ | _ | 3.50 | mA |
| | | VIN = 0V | VUFB-\ | UFS, VVFB-VVFS, VWFB-VWFS | _ | _ | 1.30 | mA |
| VFOH | Fault output voltage | Vsc = 0V, Fo circuit pull-up to 5V with $10k\Omega$ | | | 4.9 | _ | _ | V |
| VFOL | Fault output voltage | VSC = 1V, IFO = 1mA | | _ | _ | 1.10 | V | |
| VSC(ref) | Short circuit trip level | Tj = 25°C, VD = 15 | $T_j = 25^{\circ}C, V_D = 15V$ (Note 4) | | 0.43 | 0.48 | 0.53 | ٧ |
| lin | Input current | VIN = 5V | | 0.7 | 1.5 | 2.0 | mA | |
| UVDBt | | | | Trip level | 10.0 | _ | 12.0 | V |
| UVDBr | Supply circuit under-voltage | T _i ≤ 125°C | | Reset level | 10.5 | _ | 12.5 | V |
| UVDt | protection | 1j≤ 125 C | | Trip level | 10.3 | _ | 12.5 | V |
| UVDr | | | | Reset level | 10.8 | _ | 13.0 | ٧ |
| tFO | Fault output pulse width | CFO = 22nF (Note 5) | | 1.6 | 2.4 | _ | ms | |
| Vth(on) | ON threshold voltage | Applied between UP, VP, WP-VPC, UN, VN, WN-VNC | | 2.0 | 3.0 | 4.2 | V | |
| Vth(off) | OFF threshold voltage | | | 0.8 | 1.4 | 2.0 | V | |

Note 4: Short circuit protection is functioning only at the low-arms. Please select the value of the external shunt resistor such that the SC trip-level is less than 1.7 times device current rating.



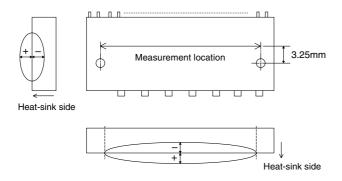
^{5:} Fault signal is output when the low-arms short circuit or control supply under-voltage protective functions operate. The fault output pulsewidth tFO depends on the capacitance value of CFO according to the following approximate equation: CFO = 9.3 × 10⁻⁶ × tFO [F].

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MECHANICAL CHARACTERISTICS AND RATINGS

| Davamatar | Condition | | Limits | | | Limit |
|--------------------|--|-----------|-----------------|----|------|-------|
| Parameter | Co | Condition | | | Max. | Unit |
| Mounting torque | Mounting screw : M4 Recommended 1.18 N·m | | 0.98 | _ | 1.47 | N·m |
| Weight | nt | | _ | 77 | _ | g |
| Heat-sink flatness | (Note 6) | | - 50 | _ | 100 | μm |

www.DataSheet4 Note 6: Measurement point of heat-sink flatness



RECOMMENDED OPERATION CONDITIONS

| Cumple al | Davamatav | Condition | | | Limits | | Unit |
|-----------------------------|---------------------------------|--|----------------|------|--------|------|------|
| Symbol | Parameter | | | Min. | Тур. | Max. | |
| Vcc | Supply voltage | Applied between P-NU, NV, NW | | 350 | 600 | 800 | V |
| VD | Control supply voltage | Applied between VP1-VPC, VN1-VNC | | 13.5 | 15.0 | 16.5 | V |
| VDB | Control supply voltage | Applied between VUFB-VUFS, VVFB-V | vfs, Vwfb-Vwfs | 13.5 | 15.0 | 16.5 | V |
| ΔV D, ΔV DB | Control supply variation | | | -1 | _ | 1 | V/µs |
| tdead | Arm shoot-through blocking time | For each input signal, Tc ≤ 100°C | | 3.3 | _ | _ | μs |
| fPWM | PWM input frequency | Tc ≤ 100°C, Tj ≤ 125°C | | _ | _ | 15 | kHz |
| lo | Output r.m.s. current | Vcc = 600V, VD = 15V, fc = 15kHz P.F = 0.8, sinusoidal PWM $T_1 \le 125^{\circ}C$, $T_1 \le 100^{\circ}C$ (Note 7) | | _ | _ | 3.4 | Arms |
| PWIN(on) | | | (Note 8) | 1.5 | _ | _ | |
| | Minimum input pulse width | $350 \le VCC \le 800V$, $13.5 \le VD \le 16.5V$, $13.5 \le VDB \le 16.5V$, | lc ≤ 10A | 2.5 | _ | _ | μs |
| PWIN(off) | | $\label{eq:continuous} \begin{array}{ll} -20^{\circ}\text{C} \leq \text{Tc} \leq 100^{\circ}\text{C}, \\ \text{N line wiring inductance less than} \\ 10\text{nH} & \text{(Note 9)} \end{array}$ | 10 < lc ≤ 17A | 2.7 | _ | _ | |
| VNC | VNC variation | Between VNC-NU, NV, NW (including | surge) | -5.0 | l – | 5.0 | V |

Note 7: The output r.m.s. current value depends on the actual application conditions.

8: DIP-IPM might not make response to the input on signal with pulse width less than PWIN (on).

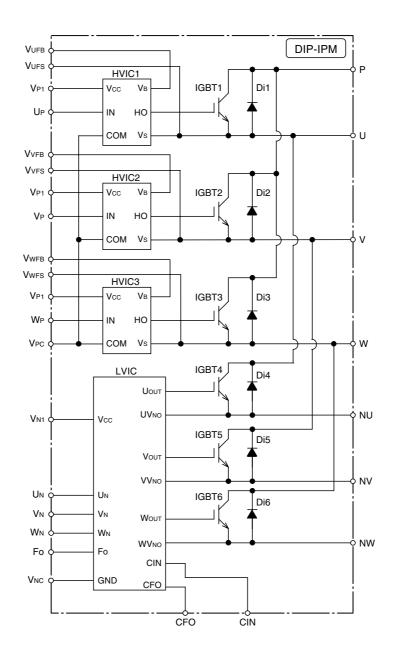
9: DIP-IPM might not make response or work properly if the input off signal pulse width is less than PWIN (off).



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Fig. 4 THE DIP-IPM INTERNAL CIRCUIT

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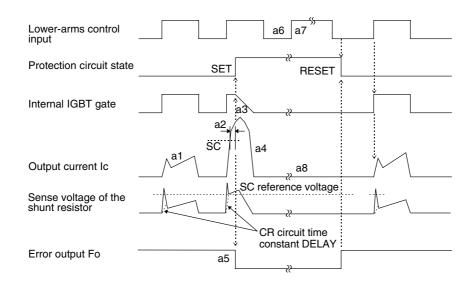
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Fig. 5 TIMING CHARTS OF THE DIP-IPM PROTECTIVE FUNCTIONS

[A] Short-Circuit Protection (Lower-arms only with the external shunt resistor and CR filter)

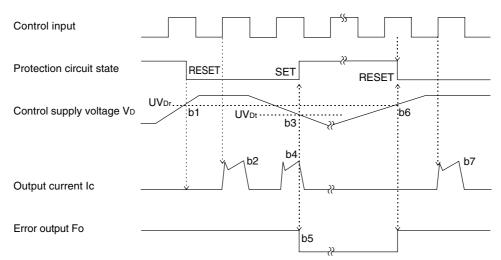
- a1. Normal operation: IGBT ON and carrying current.
- a2. Short circuit current detection (SC trigger).
- a3. IGBT gate hard interruption.
- a4. IGBT turns OFF.
- a5. Fo output with a fixed pulse width determined by the external capacitor CFO.
- a6. Input = "L": IGBT OFF
- a7. Input = "H":
- a8. IGBT OFF state in spite of input "H".

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[B] Under-Voltage Protection (Lower-arm, UVD)

- b1. Control supply voltage rising: After the voltage level reaches UVDr, the circuits start to operate when next input is applied.
- b2. Normal operation: IGBT ON and carrying current.
- b3. Under voltage trip (UVDt).
- b4. IGBT OFF in spite of control input condition.
- b5. Fo keeps output during the UV period, however, Fo pulse is not less than the fixed width for very short UV interval.
- b6. Under voltage reset (UVDr).
- b7. Normal operation: IGBT ON and carrying current.





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[C] Under-Voltage Protection (Upper-side, UVDB)

- c1. Control supply voltage rises: After the voltage reaches UVDBr, the circuits start to operate when next input is applied. c2. Normal operation: IGBT ON and carrying current.
- c3. Under voltage trip (UVDBt).
- c4. IGBT OFF in spite of control input signal level, but there is no Fo signal output.
- c5. Under voltage reset (UVDBr)
- c6. Normal operation: IGBT ON and carrying current.

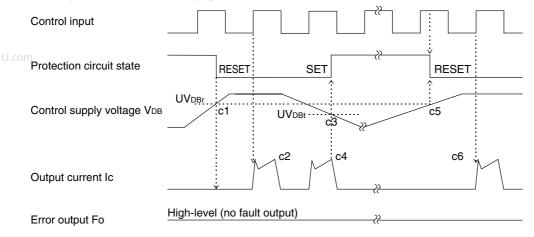
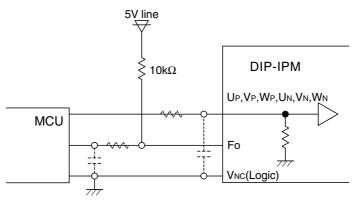
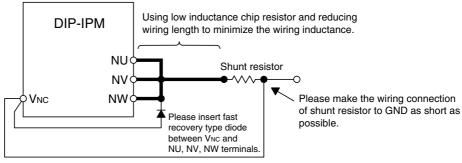


Fig. 6 MCU I/O INTERFACE CIRCUIT



Note: RC coupling at each input (parts shown dotted) may change depending on the PWM control scheme used in the application and the wiring impedance of the application's printed circuit board. The DIP-IPM input signal section integrates a 2.5k Ω (min) pull-down resistor. Therefore, when using a external filtering resistor, pay attention to the turn-on threshold voltage requirement.

Fig. 7 WIRING CONNECTION WITH 1 SHUNT RESISTOR



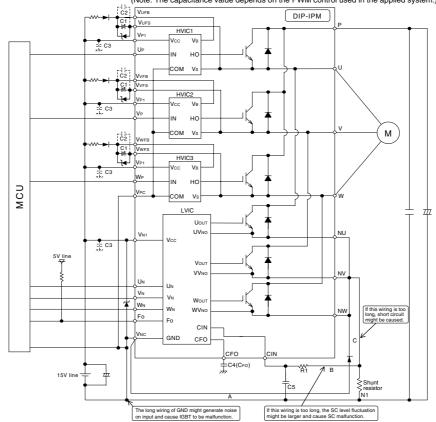
For 3 shunt resistors connection, please refer to Fig.9.



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Fig. 8 AN EXAMPLE OF TYPICAL DIP-IPM APPLICATION CIRCUT WITH 1 SHUNT RESISTOR

C1:Tight tolerance temp-compensated electrolytic type C2,C3: 0.1~0.22µF R-category ceramic capacitor for noise filtering. (Note: The capacitance value depends on the PWM control used in the applied system.)



- Note 1: To avoid malfunction, the wiring of each input should be as short as possible. (less than 2-3cm)
 2: By virtue of integrating HVIC inside the module, direct coupling to MCU terminals without any opto-coupler or transformer isolation is possible.
 3: Fo output is open drain type. The signal line should be pulled up to the positive side of a 5V supply with an approximate 10kΩ resistor.

 - 4: Fo output pulse width (tFo) should be determined by connecting external capacitor C4 between CFO and VNc terminals. (Example:

 - 4: Fo output pulse width (IFO) should be determined by connecting characteristics. Ams(typ.) at CFO=22nF)
 5: Input signal is High-Active type. There is a 2.5kΩ (Min.) resistor inside IC to pull down each input signal line to GND. When employing RC coupling circuits at each input, set up RC couple such that input signal agree with turn-off/turn-on threshold voltage.
 6: To prevent errors of the protection function, the wiring of A, B, C should be as short as possible.
 7: The time constant R5C1 of the protection circuit should be selected in the range of 1.5~2μs. SC interrupting time might vary with the interpretation. wiring pattern.
 - 8: All capacitors should be mounted as close to the terminals of the DIP-IPM as possible
 - 9: To prevent surge destruction, the wiring between the smoothing capacitor and the P&N1 terminals should be as short as possible. Generally a 0.1~0.22µF snubber between the P&N1 terminals is recommended.
 - 10: It is recommended to insert a Zener diode (24V/1W) between each pair of control supply terminals to prevent surge destruction.
 - 11: To prevent LVIC from surge destruction, it is recommended to mount a fast recovery type diode between VNC and NU, NV, NW terminals.

Fig. 9 EXAMPLE OF EXTERNAL PROTECTION CIRCUIT WITH 3 SHUNT RESISTORS

